Version: B15



# **N-Channel Power MOSFET**

100V, 81A, 10mΩ

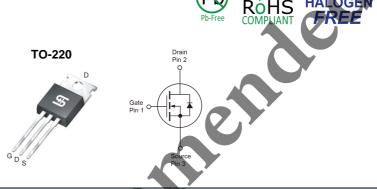
#### **FEATURES**

- Advanced Trench Technology
- 100% avalanche tested

#### **APPLICATION**

- Synchronous Rectification in SMPS
- High Speed Power Switching

KEY PERFORMANCE PARAMETERS			
PARAMETER	VALUE	UNIT	
$V_{DS}$	100	V	
R <sub>DS(on)</sub> (max)	10	mΩ	
$Q_g$	154	nC	



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	Limit	UNIT	
Drain-Source Voltage		V <sub>DS</sub>	100	V	
Gate-Source Voltage		V <sub>GS</sub>	±25	V	
	$T_C = 25^{\circ}C$		81	^	
Continuous Drain Current (Note 1)	$T_C = 70^{\circ}C$		65	A	
	T <sub>A</sub> = 25°C		8.7		
	T <sub>A</sub> = 70°C		7	Α	
Pulsed Drain Current (Note 2)		I <sub>DM</sub>	320	А	
Total Power Dissipation	$T_C = 25^{\circ}C$		210	10/	
	$T_C = 70^{\circ}C$		130	W	
	$T_A = 25$ °C	P <sub>DTOT</sub>	2.4	14/	
	$T_A = 70$ °C		1.5	W	
Single Pulsed Avalanche Energy (Note 3)		E <sub>AS</sub> , E <sub>AR</sub>	620	mJ	
Single Pulsed Avalanche Current (Note 3)		I <sub>AS</sub> , I <sub>AR</sub>	64	А	
Operating Junction and Storage Temperat	ure Range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to +150	°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	Limit	UNIT	
Junction to Case Thermal Resistance	R <sub>eJC</sub>	0.6	°C/W	
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	52.5	°C/W	

**Notes:**  $R_{\Theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\Theta JA}$  is guaranteed by design while  $R_{\Theta CA}$  is determined by the user's board design.  $R_{\Theta JA}$  shown below for single device operation on FR-4 PCB in still air.



<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>A</sub> = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 4)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV <sub>DSS</sub>	100			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	$V_{GS(TH)}$	2	3	4	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I <sub>GSS</sub>			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = 80V, V_{GS} = 0V$	I <sub>DSS</sub>			1	μA
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 40A$	R <sub>DS(ON)</sub>		9 🔌	10	mΩ
Dynamic (Note 5)						
Total Gate Charge	\/ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	$Q_g$		154	<u> </u>	
Gate-Source Charge	$V_{DS} = 30V, I_D = 40A,$ $V_{GS} = 10V$	$Q_gs$		4		nC
Gate-Drain Charge	V <sub>GS</sub> = 10V	$Q_gd$	(	45		
Input Capacitance		C <sub>iss</sub>	<b>A</b>	3900		
Output Capacitance	$V_{DS} = 30V, V_{GS} = 0V,$	Coss		300		pF
Reverse Transfer Capacitance	f = 1.0MHz	C <sub>rss</sub>		170		
Gate Resistance	F = 1MHz, open drain	$R_g$		1.2		Ω
Switching (Note 6)						
Turn-On Delay Time		t <sub>d(on)</sub>		38		
Turn-On Rise Time	$V_{DS} = 30V,$ $R_{GEN} = 6\Omega,$ $I_{D} = 1A, V_{GS} = 10V$	t <sub>r</sub>		65		
Turn-Off Delay Time		t <sub>d(off)</sub>		218		ns
Turn-Off Fall Time	ID= IM, VGS= TOV	t <sub>f</sub>		72		
Source-Drain Diode (Note 4)						
Forward Voltage	$I_S = 20A$ , $V_{GS} = 0V$	$V_{SD}$		0.8	1.2	V
Reverse Recovery Time	$I_S = 40A$ , $T_J = 25^{\circ}C$	t <sub>rr</sub>		62		ns
Reverse Recovery Charge	$dI_F/dt = 100A/\mu s$	Q <sub>rr</sub>		130		nC

### Notes:

- 1. Current limited by package
- Pulse width limited by the maximum junction temperature
- 3. L = 0.3mH,  $I_{AS}$  = 64A,  $V_{DD}$  = 50V,  $R_G$  = 25 $\Omega$ , Starting  $T_J$  = 25 $^{\circ}C$
- 4. Pulse test: PW  $\leq$  300 $\mu$ s, duty cycle  $\leq$  2%
- 5. For DESIGN AID ONLY, not subject to production testing.
- 6. Switching time is essentially independent of operating temperature.



### **ORDERING INFORMATION**

PART NO.	PACKAGE	PACKING
TSM85N10CZ C0G	TO-220	50pcs / Tube

#### Note:

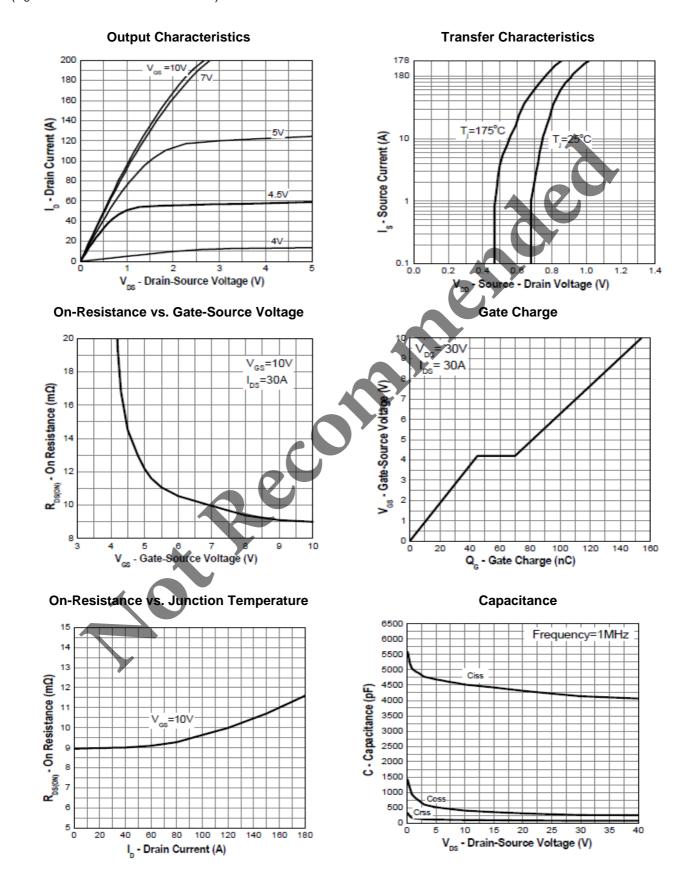
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition





## **CHARACTERISTICS CURVES**

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$ 

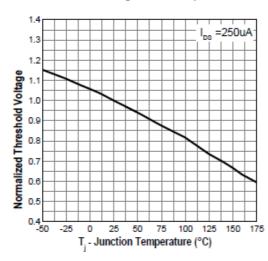




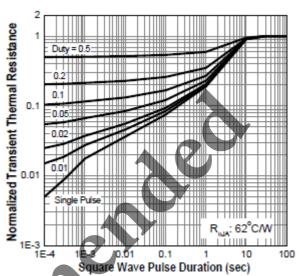
# **CHARACTERISTICS CURVES**

 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$ 

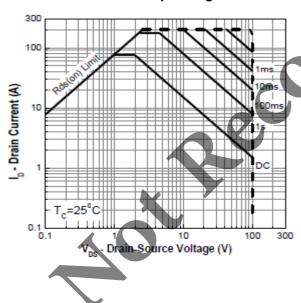
## Threshold Voltage vs. Temperature



# **Normalized Thermal Transient Impedance**

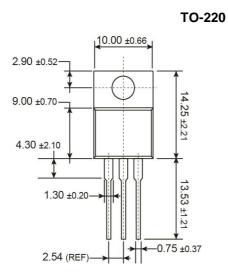


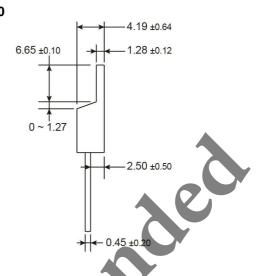
### **Maximum Safe Operating Area**



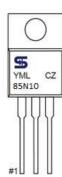


# PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)





## **MARKING DIAGRAM**



Y = Year Code

**M** = Month Code for Halogen Free Product

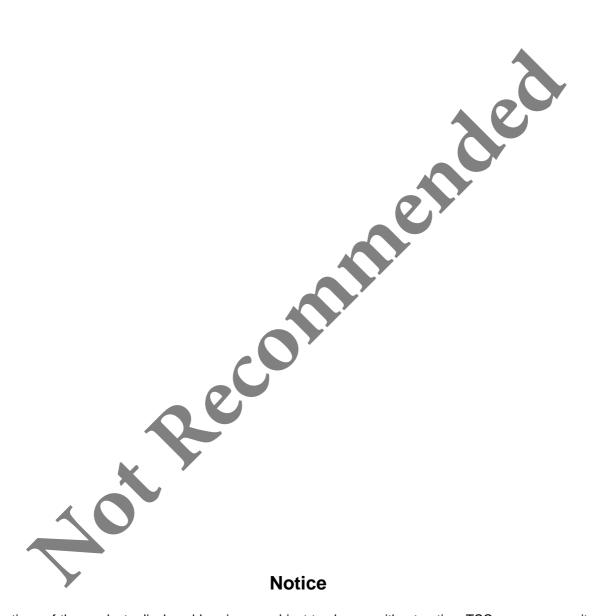
O =Jan P =Feb Q =Mar R =

S =May T =Jun U =Jul V =Aug

W = Sep X = Oct Y = Nov Z = Dec

L = Lot Code (1~9, A~Z)





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